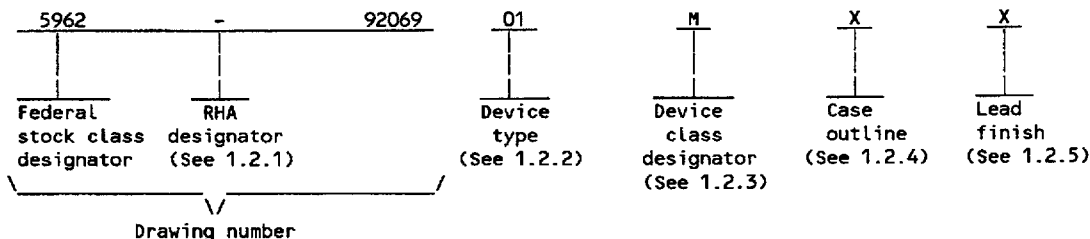


1. SCOPE

1.1 Scope. This drawing forms a part of a one part - one part number documentation system (see 6.6 herein). Two product assurance classes consisting of military high reliability (device classes B, Q, and M) and space application (device classes S and V), and a choice of case outlines and lead finishes are available and are reflected in the Part or Identifying Number (PIN). Device class M microcircuits represent non-JAN class B microcircuits in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices". When available, a choice of radiation hardness assurance (RHA) levels are reflected in the PIN.

1.2 PIN. The PIN shall be as shown in the following example:



1.2.1 Radiation hardness assurance (RHA) designator. Device classes M, B, and S RHA marked devices shall meet the MIL-M-38510 specified RHA levels and shall be marked with the appropriate RHA designator. Device classes Q and V RHA marked devices shall meet the MIL-I-38535 specified RHA levels and shall be marked with the appropriate RHA designator. A dash (-) indicates a non-RHA device.

1.2.2 Device type(s). The device type(s) shall identify the circuit function as follows:

Device type	Generic number 1/	Circuit function	Access time
01		4K x 9-bit parallel-to-serial FIFO	120 ns
02		4K x 9-bit parallel-to-serial FIFO	80 ns
03		4K x 9-bit parallel-to-serial FIFO	65 ns
04		4K x 9-bit parallel-to-serial FIFO	50 ns
05		4K x 9-bit parallel-to-serial FIFO	40 ns

1.2.3 Device class designator. The device class designator shall be a single letter identifying the product assurance level as follows:

Device class	Device requirements documentation
M	Vendor self-certification to the requirements for non-JAN class B microcircuits in accordance with 1.2.1 of MIL-STD-883
B or S	Certification and qualification to MIL-M-38510
Q or V	Certification and qualification to MIL-I-38535

1.2.4 Case outline(s). The case outline(s) shall be as designated in MIL-STD-1835 and as follows:

Outline letter	Descriptive designator	Terminals	Package style
X	CDIP2-T28	28	Dual-in-line
Y	CDFP3-F28	28	Flat pack

1.2.5 Lead finish. The lead finish shall be as specified in MIL-M-38510 for classes M, B, and S or MIL-I-38535 for classes Q and V. Finish letter "X" shall not be marked on the microcircuit or its packaging. The "X" designation is for use in specifications when lead finishes A, B, and C are considered acceptable and interchangeable without preference.

1/ Generic numbers are listed on the Standardized Military Drawing Source Approval Bulletin at the end of this document and will also be listed in MIL-BUL-103.

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1.3 Absolute maximum ratings. 2/ 3/

Terminal voltage range with respect to ground - - - -	-0.5 V dc to +7.0 V dc
DC output current (I_{OUT}) - - - - -	50 mA
Storage temperature range - - - - -	-65°C to +150°C
Lead temperature (soldering, 10 seconds) - - - - -	+260°C
Thermal resistance, junction-to-case (θ_{JC}) - - - - -	See MIL-STD-1835
Maximum power dissipation (P_D) - - - - -	1.0 watt
Junction temperature (T_J) - - - - -	+175°C 4/

1.4 Recommended operating conditions.

Supply voltage range (V_{CC}) - - - - -	4.5 V dc to 5.5 V dc
Supply voltage (V_{SS}) - - - - -	0.0 V dc
High level input voltage (V_{IH}) - - - - -	2.2 V dc minimum
Low level input voltage (V_{IL}) - - - - -	0.8 V dc maximum 4/
Case operating temperature range (T_C) - - - - -	-55°C to +125°C

1.5 Digital logic testing for device classes Q and V.

Fault coverage measurement of manufacturing logic tests (MIL-STD-883, test method 5012) - - - -	6/ percent
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2. APPLICABLE DOCUMENTS

2.1 Government specifications, standards, bulletin, and handbook. Unless otherwise specified, the following specifications, standards, bulletin, and handbook of the issue listed in that issue of the Department of Defense Index of Specifications and Standards specified in the solicitation, form a part of this drawing to the extent specified herein.

SPECIFICATIONS

MILITARY

MIL-M-38510	-	Microcircuits, General Specification for.
MIL-I-38535	-	Integrated Circuits, Manufacturing, General Specification for.

STANDARDS

MILITARY

MIL-STD-480	-	Configuration Control-Engineering Changes, Deviations and Waivers.
MIL-STD-883	-	Test Methods and Procedures for Microelectronics.
MIL-STD-1835	-	Microcircuit Case Outlines.

BULLETIN

MILITARY

MIL-BUL-103	-	List of Standardized Military Drawings (SMD's).
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2/ Stresses above the absolute maximum rating may cause permanent damage to the device. Extended operation at the maximum levels may degrade performance and affect reliability.

3/ All voltages referenced to V_{SS} (V_{SS} = ground) unless otherwise specified.

4/ Maximum junction temperature shall not be exceeded except for allowable short duration burn-in screening conditions in accordance with method 5004 of MIL-STD-883.

5/ Negative undershoots to a minimum of -1.5 V are allowed with a maximum of 10 ns pulse width.

6/ When a QML source exists, a value shall be provided.

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HANDBOOK

MILITARY

MIL-HDBK-780 - Standardized Military Drawings.

(Copies of the specifications, standards, bulletin, and handbook required by manufacturers in connection with specific acquisition functions should be obtained from the contracting activity or as directed by the contracting activity.)

2.2 Non-Government publications. The following document(s) form a part of this document to the extent specified herein. Unless otherwise specified, the issues of the documents which are DoD adopted are those listed in the issue of the DODISS cited in the solicitation. Unless otherwise specified, the issues of documents not listed in the DODISS are the issues of the documents cited in the solicitation.

AMERICAN SOCIETY FOR TESTING AND MATERIALS (ASTM)

ASTM Standard F1192-88 - Standard Guide for the Measurement of Single Event Phenomena from Heavy Ion Irradiation of Semiconductor Devices.

(Applications for copies of ASTM publications should be addressed to the American Society for Testing and Materials, 1916 Race Street, Philadelphia, PA 19103.)

ELECTRONICS INDUSTRIES ASSOCIATION (EIA)

JEDEC Standard No. 17 - A Standardized Test Procedure for the Characterization of Latch-up in CMOS Integrated Circuits.

(Applications for copies should be addressed to the Electronics Industries Association, 2001 Pennsylvania Street, N.W., Washington, DC 20006.)

(Non-Government standards and other publications are normally available from the organizations that prepare or distribute the documents. These documents also may be available in or through libraries or other informational services.)

2.3 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence.

3. REQUIREMENTS

3.1 Item requirements. The individual item requirements for device class M shall be in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices" and as specified herein. The individual item requirements for device classes B and S shall be in accordance with MIL-M-38510 and as specified herein. For device classes B and S, a full electrical characterization table for each device type shall be included in this SMD. The individual item requirements for device classes Q and V shall be in accordance with MIL-I-38535, the device manufacturer's Quality Management (QM) plan, and as specified herein.

3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-M-38510 for device classes M, B, and S and MIL-I-38535 for device classes Q and V and herein.

3.2.1 Case outline(s). The case outline(s) shall be in accordance with 1.2.4.

3.2.2 Terminal connections. The terminal connections shall be as specified on figure 1.

3.2.3 Truth table. The truth table shall be as specified on figure 2.

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3.3 Electrical performance characteristics and postirradiation parameter limits. Unless otherwise specified herein, the electrical performance characteristics and postirradiation parameter limits are as specified in table I and shall apply over the full case operating temperature range.

3.4 Electrical test requirements. The electrical test requirements shall be the subgroups specified in table IIA. The electrical tests for each subgroup are defined in table I.

3.5 Marking. The part shall be marked with the PIN listed in 1.2 herein. Marking for device class M shall be in accordance with MIL-STD-883 (see 3.1 herein). In addition, the manufacturer's PIN may also be marked as listed in MIL-BUL-103. Marking for device classes B and S shall be in accordance with MIL-M-38510. Marking for device classes Q and V shall be in accordance with MIL-I-38535.

3.5.1 Certification/compliance mark. The compliance mark for device class M shall be a "C" as required in MIL-STD-883 (see 3.1 herein). The certification mark for device classes B and S shall be a "J" or "JAN" as required in MIL-M-38510. The certification mark for device classes Q and V shall be a "QML" as required in MIL-I-38535.

3.6 Certificate of compliance. For device class M, a certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-BUL-103 (see 6.7.3 herein). For device classes Q and V, a certificate of compliance shall be required from a QML-38535 listed manufacturer in order to supply to the requirements of this drawing (see 6.7.2 herein). The certificate of compliance submitted to DESC-EC prior to listing as an approved source of supply for this drawing shall affirm that the manufacturer's product meets, for device class M the requirements of MIL-STD-883 (see 3.1 herein), or for device classes Q and V, the requirements of MIL-I-38535 and the requirements herein.

3.7 Certificate of conformance. A certificate of conformance as required for device class M in MIL-STD-883 (see 3.1 herein) or device classes B and S in MIL-M-38510 or for device classes Q and V in MIL-I-38535 shall be provided with each lot of microcircuits delivered to this drawing.

3.8 Notification of change for device class M. For device class M, notification to DESC-EC of change of product (see 6.2 herein) involving devices acquired to this drawing is required for any change as defined in MIL-STD-480.

3.9 Verification and review for device class M. For device class M, DESC, DESC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.

3.10 Microcircuit group assignment for device classes M, B, and S. Device classes M, B, and S devices covered by this drawing shall be in microcircuit group number 105 (see MIL-M-38510, appendix E).

3.11 Serialization for device class S and V. All device class S devices shall be serialized in accordance with MIL-M-38510. Class V shall be serialized in accordance with MIL-I-38535.

4. QUALITY ASSURANCE PROVISIONS

4.1 Sampling and inspection. For device class M, sampling and inspection procedures shall be in accordance with section 4 of MIL-M-38510 to the extent specified in MIL-STD-883 (see 3.1 herein). For device classes B and S, sampling and inspection procedures shall be in accordance with MIL-M-38510 and method 5005 of MIL-STD-883, except as modified herein. For device classes Q and V, sampling and inspection procedures shall be in accordance with MIL-I-38535 and the device manufacturer's QM plan.

4.2 Screening. For device class M, screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. For device classes B and S, screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to qualification and quality conformance inspection. For device classes Q and V, screening shall be in accordance with MIL-I-38535, and shall be conducted on all devices prior to qualification and technology conformance inspection.

4.2.1 Additional criteria for device classes M, B, and S.

- a. Delete the sequence specified as initial (preburn-in) electrical parameters through interim (postburn-in) electrical parameters of method 5004 and substitute lines 1 through 6 of table IIA herein.

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TABLE I. Electrical performance characteristics.

Test	Symbol	Conditions $-55^{\circ}\text{C} \leq T_C \leq +125^{\circ}\text{C}$ $V_{SS} = 0\text{ V}; 4.5\text{ V} \leq V_{CC} \leq 5.5\text{ V}$ unless otherwise specified	Group A subgroups	Device types	Limits		Unit
					Min	Max	
Input leakage current	I_{LI}	$0.4\text{ V} \leq V_{IN} \leq V_{CC}$	1,2,3	ALL	-10	10	μA
Output leakage current	I_{LO}	$\text{SOCP} \leq V_{IL},$ $0.4\text{ V} \leq V_{OUT} \leq V_{CC}$	1,2,3	ALL	-10	10	μA
Output high voltage	V_{OH}	$I_{OUT} = -8.0\text{ mA}$	1,2,3	ALL	2.4		V
Output low voltage	V_{OL}	$I_{OUT} = 16\text{ mA}$	1,2,3	ALL		0.4	V
Power supply current	I_{CC1}	$f = f_S$, outputs open, $V_{CC} = 5.5\text{ V}$	1,2,3	ALL		160	mA
Average standby current	I_{CC2}	$\bar{W} = \bar{RS} = \overline{FL/RT} = V_{IH},$ $\text{SOCP} = V_{IL}$, outputs open	1,2,3	ALL		25	mA
Power down current	I_{CC3}	$\bar{RS} = \overline{FL/RT} = \bar{W} = V_{CC} - 0.2\text{ V},$ $\text{SOCP} \leq 0.2\text{ V}$, all other inputs $\geq V_{CC} - 0.2\text{ V}$ or $\leq 0.2\text{ V}$, outputs open	1,2,3	ALL		4.0	mA
Input capacitance	C_{IN}	$V_{IN} = 0\text{ V}$, $f = 1.0\text{ MHz}$, $T_A = +25^{\circ}\text{C}$, see 4.4.1e	4	ALL		10	pF
Output capacitance	C_{OUT}	$V_{OUT} = 0\text{ V}$, $f = 1.0\text{ MHz}$, $T_A = +25^{\circ}\text{C}$, see 4.4.1e	4	ALL		12	pF
Functional test		See 4.4.1c	7,8A,8B	ALL			
Parallel shift frequency	f_S	$C_L = 30\text{ pF}$, see figures 3 and 4	9,10,11	01		7.0	MHz
				02		10	
				03		12.5	
				04		15	
				05		20	

See footnotes at end of table.

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TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions $-55^{\circ}\text{C} \leq T_C \leq +125^{\circ}\text{C}$ $V_{SS} = 0\text{ V}; 4.5\text{ V} \leq V_{CC} \leq 5.5\text{ V}$ unless otherwise specified	Group A subgroups	Device types	Limits		Unit
					Min	Max	
Serial-out shift frequency	f_{SOCP}	$C_L = 30\text{ pF}$, see figures 3 and 4	9,10,11	01		25	MHz
				02		28	
				03		33	
				04		40	
				05		50	

PARALLEL INPUT TIMINGS

Data setup time	t_{DS}	$C_L = 30\text{ pF}$, see figures 3 and 4	9,10,11	01,02	40		ns
				03,04	30		
				05	20		
Data hold time	t_{DH}		9,10,11	01-03	10		ns
				04	5.0		
				05	0		
Write cycle time	t_{WC}		9,10,11	01	140		ns
				02	100		
				03	80		
				04	65		
				05	50		

See footnote at end of table.

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TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions -55°C ≤ T _C ≤ +125°C V _{SS} = 0 V; 4.5 V ≤ V _{CC} ≤ 5.5 V unless otherwise specified	Group A subgroups	Device types	Limits		Unit
					Min	Max	

PARALLEL INPUT TIMINGS - Continued.

Write pulse width	t _{WPW}	C _L = 30 pF, see figures 3 and 4	9,10,11	01	120		ns
				02	80		
				03	65		
				04	50		
				05	40		
Write recovery time	t _{WR}		9,10,11	01, 02	20		ns
				03, 04	15		
				05	10		
Write high to $\overline{EF}$ high	t _{WEF}		9,10,11	01- 02		60	ns
				04		45	
				05		35	
Write low to $\overline{FF}$ low	t _{WFF}		9,10,11	01- 03		60	ns
				04		45	
				05		35	

See footnotes at end of table.

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TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions $-55^{\circ}\text{C} \leq T_C \leq +125^{\circ}\text{C}$ $V_{SS} = 0\text{ V}; 4.5\text{ V} \leq V_{CC} \leq 5.5\text{ V}$ unless otherwise specified	Group A subgroups	Device types	Limits		Unit
					Min	Max	

PARALLEL INPUT TIMINGS - Continued.

Write low to transitioning $\overline{\text{HF}}$, $\overline{\text{AEF}}$	t_{WF}	$C_L = 30\text{ pF}$, see figures 3 and 4	9,10,11	01		140	ns
				02		100	
				03		80	
				04		65	
				05		50	
Write pulse width after $\overline{\text{FF}}$ high	t_{WPF}		9,10,11	01	120		ns
				02	80		
				03	65		
				04	50		
				05	40		

SERIAL OUTPUT TIMINGS

SOCP rising edge to SO at high Z_1	t_{SOHZ}	$C_L = 30\text{ pF}$, see figures 3 and 4	9,10,11	01	5.0	35	ns
				02	5.0	25	
				03	5.0	20	
				04	5.0	26	
				05	5.0	16	

See footnote at end of table.

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TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions -55°C ≤ T _C ≤ +125°C V _{SS} = 0 V; 4.5 V ≤ V _{CC} ≤ 5.5 V unless otherwise specified	Group A subgroups	Device types	Limits		Unit
					Min	Max	
SERIAL OUTPUT TIMINGS - Continued.							
SOCP rising edge to SO at low Z <u>1</u> /	t _{SOLZ}	C _L = 30 pF, see figures 3 and 4	9,10,11	01	5.0	35	ns
				02	5.0	30	
				03- 05	5.0	22	
SOCP rising edge to valid data on SO	t _{SOPD}		9,10,11	01		35	ns
				02		30	
				03		22	
				04, 05		18	
SOX setup time to SOCP rising edge	t _{SOX}		9,10,11	ALL	5.0		ns
Serial in clock width high/low	t _{SOCW}		9,10,11	01, 02	15		ns
				03, 04	10		
				05	8.0		
SOCP rising edge (bit 0 - last word) to EF low	t _{SOCEF}		9,10,11	01- 03		30	ns
				04, 05		25	

See footnote at end of table.

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TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions -55°C ≤ T _C ≤ +125°C V _{SS} = 0 V; 4.5 V ≤ V _{CC} ≤ 5.5 V unless otherwise specified	Group A subgroups	Device types	Limits		Unit
					Min	Max	

SERIAL OUTPUT TIMINGS - Continued.

SCOP rising edge to FF high	t _{SOCFF}	C _L = 30 pF, see figures 3 and 4	9,10,11	01		65	ns
				02		60	
				03		50	
				04		40	
				05		35	
SOCF rising edge to HF, AEF high	t _{SOCF}		9,10,11	01		65	ns
				02		60	
				03		50	
				04		40	
				05		35	
Recovery time SOCP after EF high	t _{REFSO}		9,10,11	01	120		ns
				02	80		
				03	65		
				04	50		
				05	40		

See footnote at end of table.

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TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions -55°C ≤ T _C ≤ +125°C V _{SS} = 0 V; 4.5 V ≤ V _{CC} ≤ 5.5 V unless otherwise specified	Group A subgroups	Device types	Limits		Unit
					Min	Max	
RESET TIMINGS							
Reset cycle time	t _{RSC}	C _L = 30 pF, see figures 3 and 4	9,10,11	01	140		ns
				02	100		
				03	80		
				04	65		
				05	50		
Reset pulse width	t _{RS}	C _L = 30 pF, see figures 3 and 4	9,10,11	01	120		ns
				02	80		
				03	65		
				04	50		
				05	40		
Reset setup time	t _{RSS}		9,10,11	01	120		ns
				02	80		
				03	65		
				04	50		
				05	40		

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TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions -55°C ≤ T _C ≤ +125°C V _{SS} = 0 V; 4.5 V ≤ V _{CC} ≤ 5.5 V unless otherwise specified	Group A subgroups	Device types	Limits		Unit
					Min	Max	
RESET TIMINGS - Continued.							
Reset recovery time	t _{RSR}	CL = 30 pF, see figures 3 and 4	9,10,11	01, 02	20		ns
				03, 04	15		
				05	10		
Reset to $\overline{EF}$ and $\overline{AEF}$ Low	t _{RSF1}		9,10,11	01		140	ns
				02		100	
				03		80	
				04		65	
				05		50	
Reset to $\overline{HF}$ and $\overline{FF}$ high	t _{RSF2}		9,10,11	01		140	ns
				02		100	
				03		80	
				04		65	
				05		50	

See footnote at end of table.

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TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions -55°C ≤ T _C ≤ +125°C V _{SS} = 0 V; 4.5 V ≤ V _{CC} ≤ 5.5 V unless otherwise specified	Group A subgroups	Device types	Limits		Unit
					Min	Max	

RESET TIMINGS - Continued

Reset to Q low	t _{RSQL}	CL = 30 pF, see figures 3 and 4	9,10,11	01	105		ns
				02	65		
				03	50		
				04	35		
				05	20		
Reset to Q high	t _{RSQH}		9,10,11	01	105		ns
				02	65		
				03	50		
				04	35		
				05	20		

RETRANSMIT TIMINGS

Retransmit cycle time	t _{RTC}	C _L = 30 pF, see figures 3 and 4	9,10,11	01	140		ns
				02	100		
				03	80		
				04	65		
				05	50		

See footnote at end of table.

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TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions $-55^{\circ}\text{C} \leq T_C \leq +125^{\circ}\text{C}$ $V_{SS} = 0\text{ V}; 4.5\text{ V} \leq V_{CC} \leq 5.5\text{ V}$ unless otherwise specified	Group A subgroups	Device types	Limits		Unit
					Min	Max	

RETRANSMIT TIMINGS - Continued.

Retransmit pulse width	t_{RT}	$C_L = 30\text{ pF}$, see figures 3 and 4	9,10,11	01	120		ns
				02	80		
				03	65		
				04	50		
				05	40		
Retransmit setup time	t_{RTS}		9,10,11	01	120		ns
				02	80		
				03	65		
				04	50		
				05	40		
Retransmit recovery time	t_{RTR}		9,10,11	01, 02	20		ns
				03, 04	15		
				05	10		

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TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions -55°C ≤ T _C ≤ +125°C V _{SS} = 0 V; 4.5 V ≤ V _{CC} ≤ 5.5 V unless otherwise specified	Group A subgroups	Device types	Limits		Unit
					Min	Max	
DEPTH EXPANSION MODE TIMINGS							
Read/write to $\overline{\text{X0}}$ low	t _{X0L}	C _L = 30 pF, see figures 3 and 4	9,10,11	01		120	ns
				02		80	
				03		65	
				04		50	
				05		40	
Read/write to $\overline{\text{X0}}$ high	t _{X0H}		9,10,11	01		120	ns
				02		80	
				03		65	
				04		50	
				05		40	
$\overline{\text{XI}}$ pulse width	t _{XI}		9,10,11	01	120		ns
				02	80		
				03	65		
				04	50		
				05	40		
$\overline{\text{XI}}$ recovery time	t _{XIR}		9,10,11	ALL	10		ns
$\overline{\text{XI}}$ setup time	t _{XIS}		9,10,11	ALL	15		ns

1/ If not tested, shall be guaranteed to the limits specified in table I.

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Device types	All	Device types	All
Case outlines	X, Y	Case outlines	X, Y
Terminal number	Terminal symbol	Terminal number	Terminal symbol
1	$\overline{W}$	15	$\overline{NR}$
2	D_4	16	Q_6
3	D_3	17	Q_7
4	D_2	18	Q_8
5	D_1	19	GND
6	D_0	20	$\overline{XO/HF}$
7	$\overline{XI}$	21	$\overline{EF}$
8	SOX	22	$\overline{RS}$
9	SOCp	23	$\overline{FL/RT}$
10	SO	24	D_8
11	$\overline{AEF}$	25	D_7
12	$\overline{FF}$	26	D_6
13	Q_4	27	D_5
14	GND	28	V_{CC}

FIGURE 1. Terminal connections.

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RESET AND RETRANSMIT
SINGLE DEVICE CONFIGURATION/WIDTH EXPANSION MODE

Mode	Inputs			Internal status		Outputs		
	$\overline{RS}$	$\overline{FL/RT}$	$\overline{XI}$	Read pointer	Write pointer	$\overline{AEF}$, $\overline{EF}$	$\overline{FF}$	$\overline{HF}$
Reset	0	X	0	Location zero	Location zero	0	1	1
Retransmit	1	0	0	Location zero	Unchanged	X	X	X
Read/write	1	1	0	Increment $\frac{1}{2}$	Increment $\frac{1}{2}$	X	X	X

$\frac{1}{2}$ Pointer will increment if appropriate flag is high.

RESET AND FIRST LOAD
DEPTH EXPANSION/COMPOUND EXPANSION MODE

Mode	Inputs			Internal status		Outputs	
	$\overline{RS}$	$\overline{FL}$	$\overline{XI}$	Read pointer	Write pointer	$\overline{EF}$	$\overline{FF}$
Reset first device	0	0	$\frac{1}{2}$	Location zero	Location zero	0	1
Reset all other devices	0	1	$\frac{1}{2}$	Location zero	Location zero	0	1
Read/write	1	X	$\frac{1}{2}$	X	X	X	X

$\frac{1}{2}$ $\overline{XI}$ is connected to $\overline{X0}$ of previous device.

STATUS FLAGS

Number of words in FIFO	$\overline{FF}$	$\overline{AEF}$	$\overline{HF}$	$\overline{EF}$
0	1	0	1	0
1 - 511	1	0	1	1
512 - 2048	1	1	1	1
2049 - 3584	1	1	0	1
3585 - 4095	1	0	0	1
4096	0	0	0	1

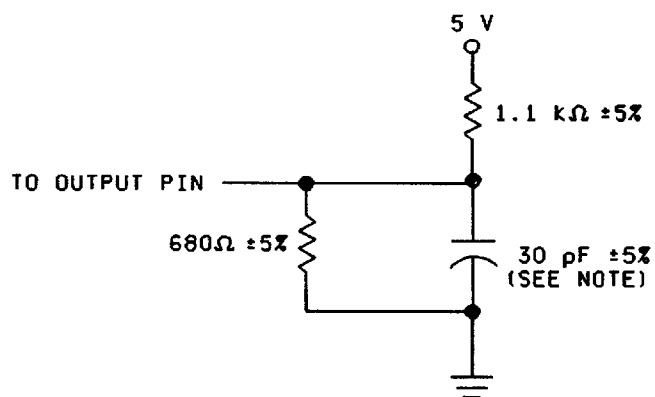
NOTE: $\overline{RS}$ = Reset input, $\overline{FL/RT}$ = First load/retransmit,
 $\overline{EF}$ = Empty flag output, $\overline{FF}$ = Full flag output,
 $\overline{XI}$ = Expansion input, and $\overline{HF}$ = Half-full flag output.
 0 = Low level voltage
 1 = High level voltage
 X = Don't care

FIGURE 2. Truth tables.

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NOTE: C_L includes scope and jig capacitance.

AC test conditions

Input pulse levels	GND to 3.0 V
Input rise and fall times	≤ 5.0 ns
Input timing reference levels	1.5 V
Output reference levels	1.5 V

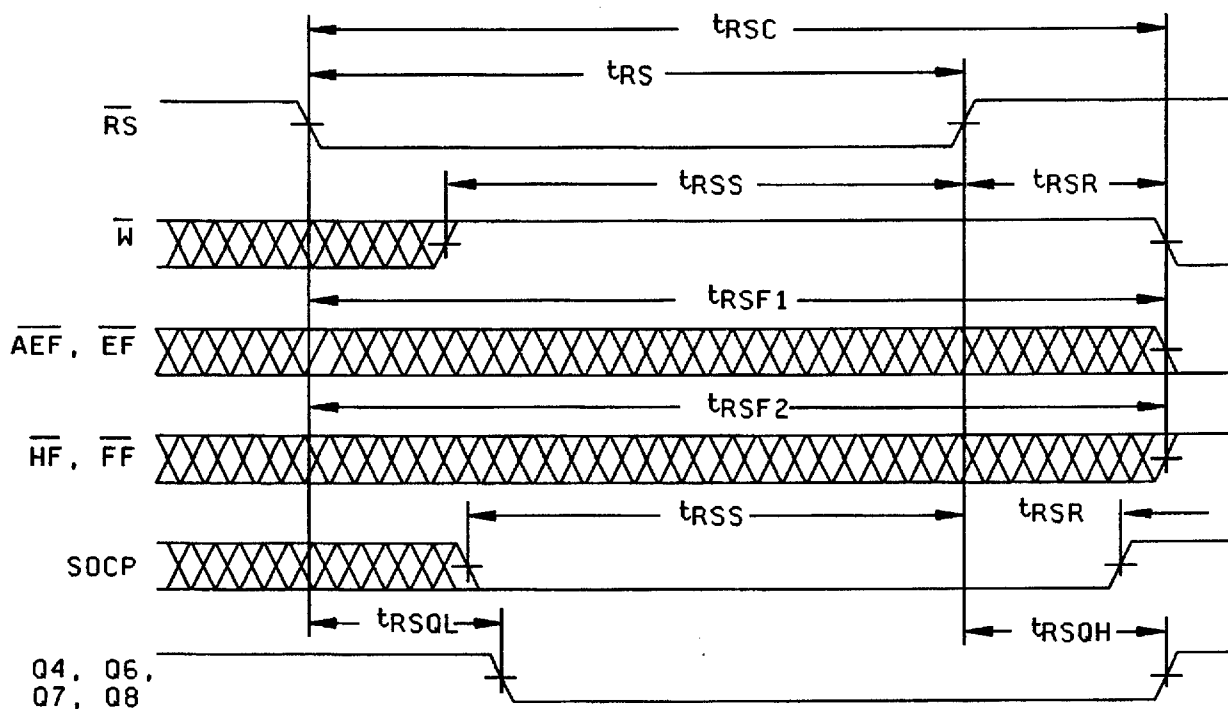
FIGURE 3. Output load circuit.

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RESET TIMING



WRITE OPERATION

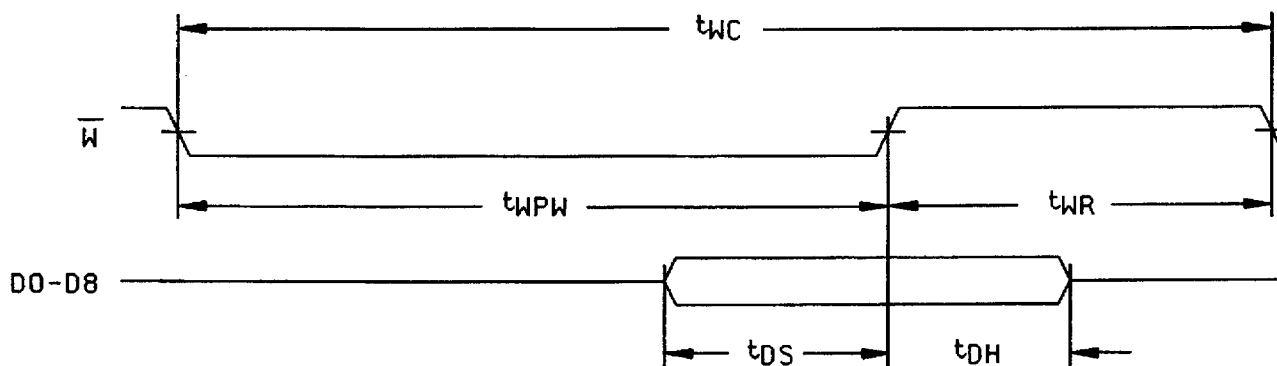


FIGURE 4. Timing waveforms.

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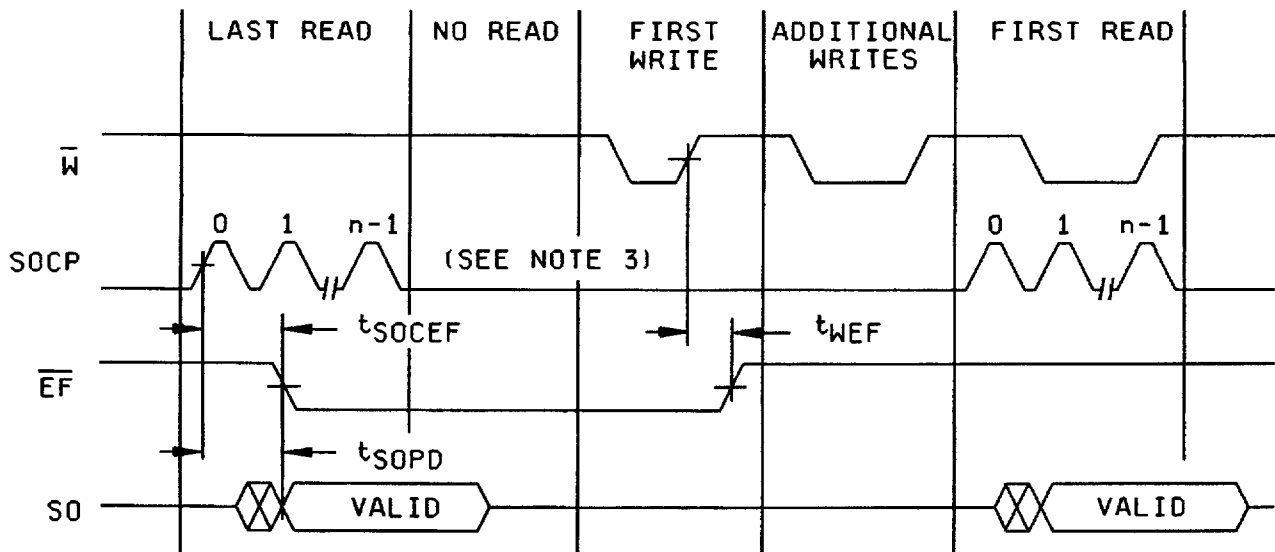
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EMPTY FLAG FROM LAST READ TO FIRST WRITE



EMPTY BOUNDARY CONDITION TIMING

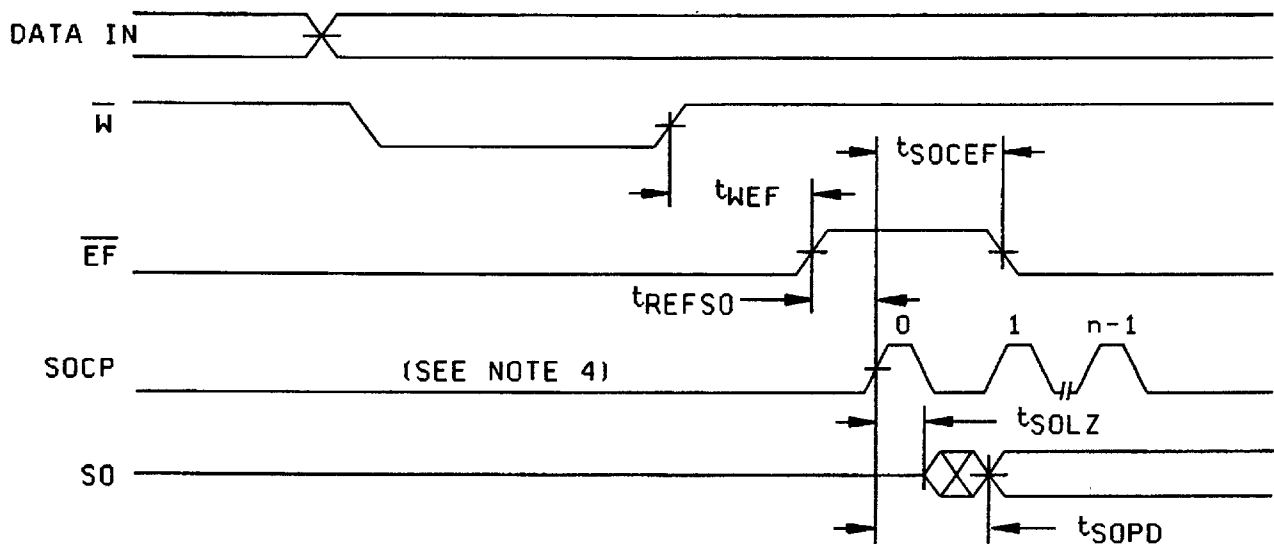


FIGURE 4. Timing waveforms - Continued.

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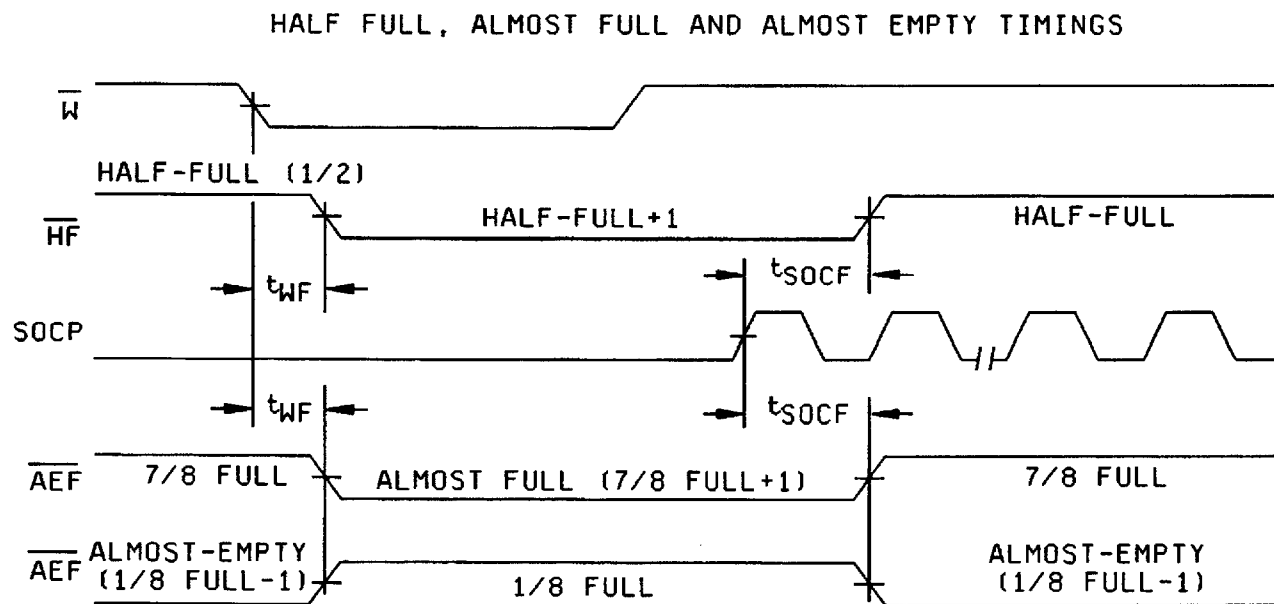
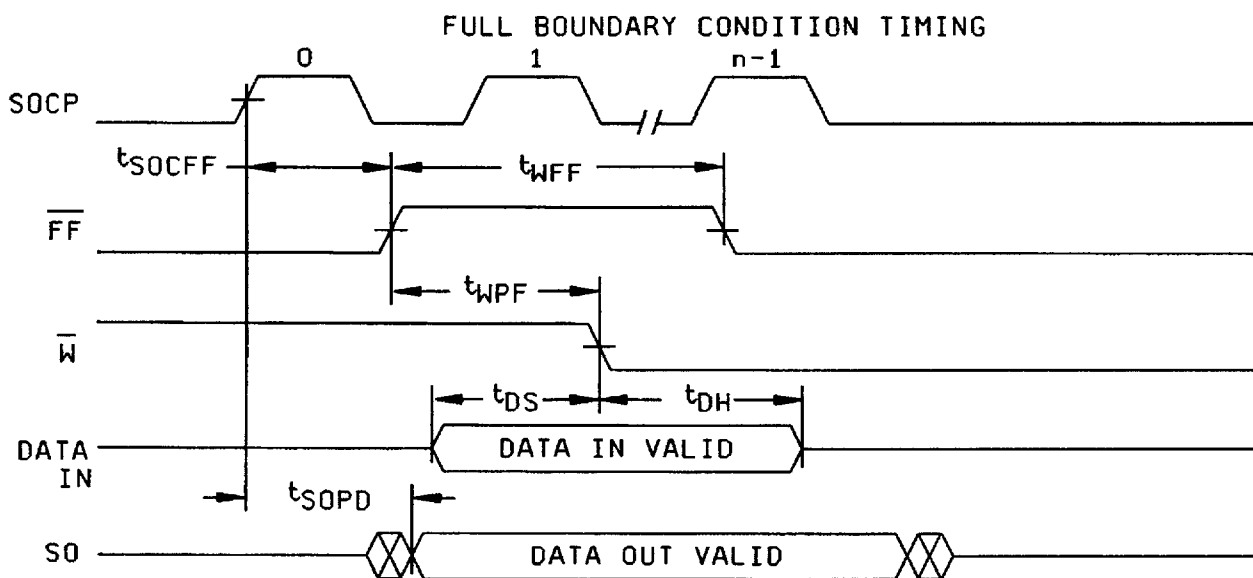


FIGURE 4. Timing waveforms - Continued.

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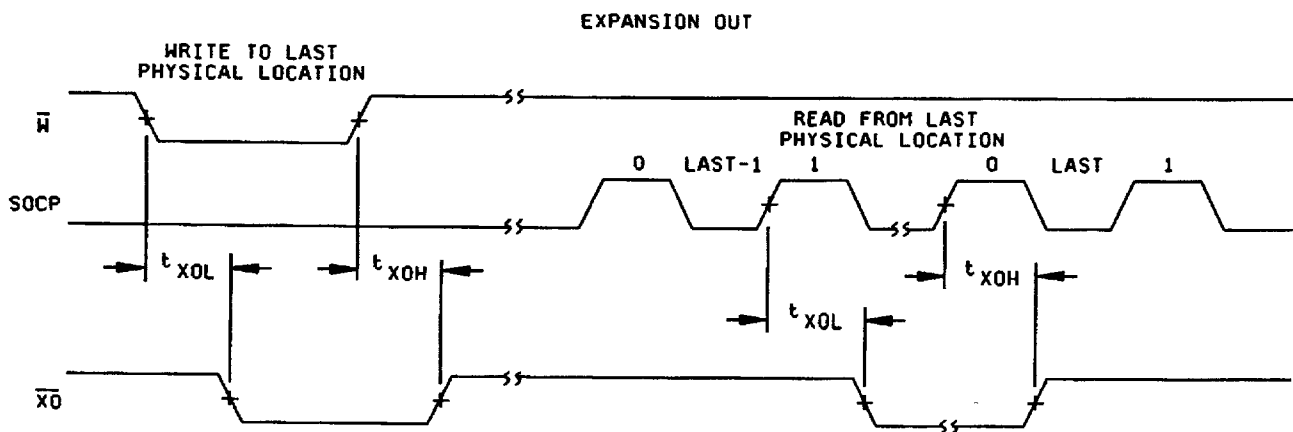
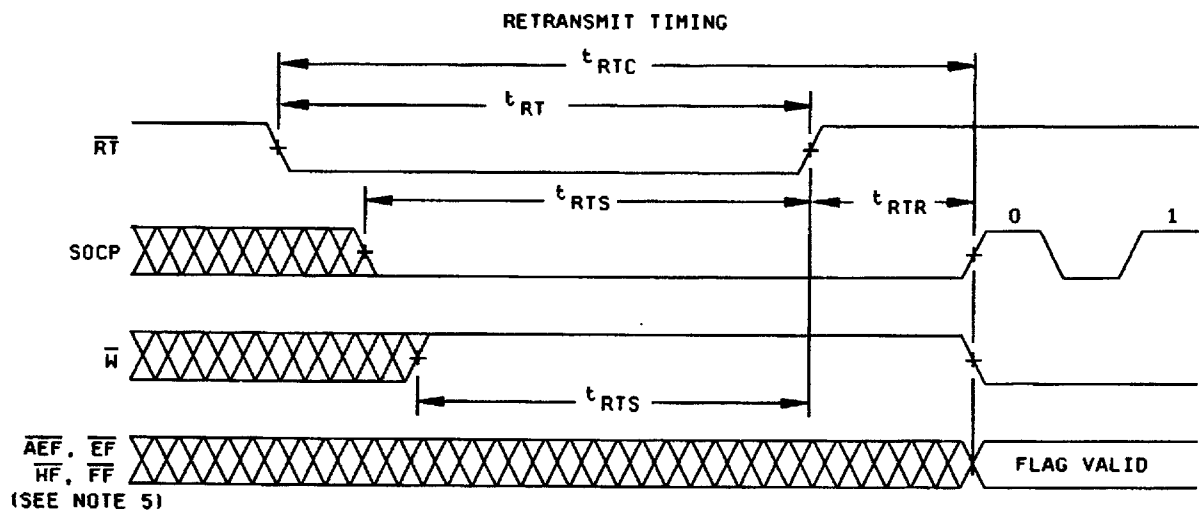


FIGURE 4. Timing waveforms - Continued.

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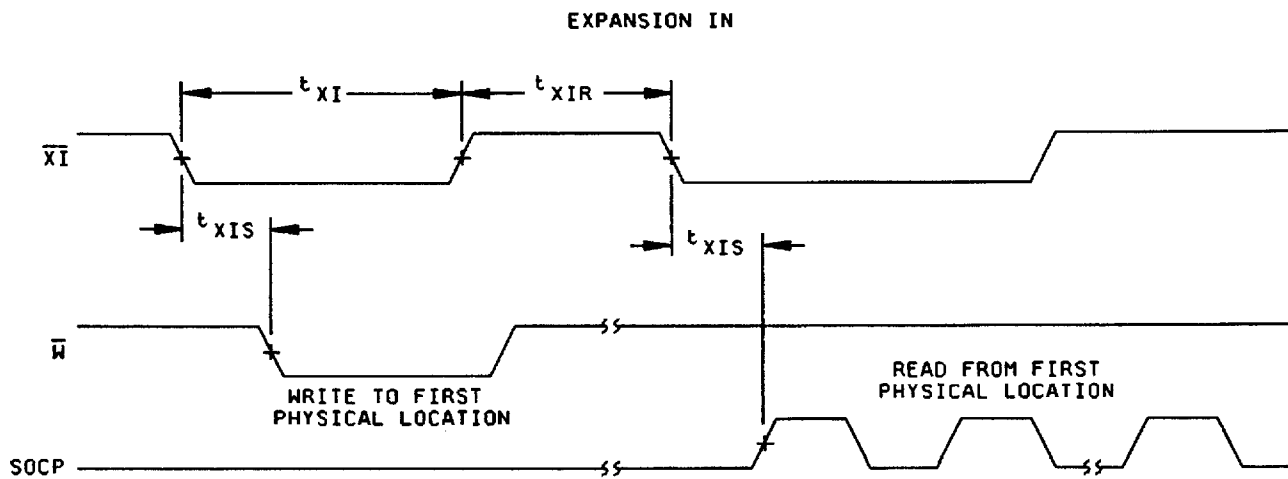
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NOTES:

1. This timing applies to the active device in width expansion mode.
2. This timing applies to single device mode at empty boundary ($EF = \text{low}$) and the next active device in width expansion mode.
3. SOCP should not be clocked until $\overline{EF}$ goes high.
4. SOCP should not be clocked until $\overline{EF}$ goes high.
5. EF , AEF , HF , and FF may change status during retransmit, but flags will be valid at t_{RTC} .

FIGURE 4. Timing waveforms - Continued.

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TABLE IIA. Electrical test requirements. 1/ 2/ 3/ 4/ 5/ 6/ 7/

Line no.	Test requirements	Subgroups (in accordance with MIL-STD-883, method 5005, table I)			Subgroups (in accordance with MIL-I-38535, table III)	
		Device class M	Device class B	Device class S	Device class Q	Device class V
1	Interim electrical parameters (see 4.2)		1,7,9	1,7,9	1,7,9	1,7,9
2	Static burn-in I and II (method 1015)	Not required	Not required	Required	Not required	Required
3	Same as Line 1			1*,7* Δ		1*,7* Δ
4	Dynamic burn-in (method 1015)	Required	Required	Required	Required	Required
5	Same as Line 1			1*,7* Δ		1*,7* Δ
6	Final electrical parameters	1*,2,3,7*, 8A,8B,9,10, 11	1*,2,3,7*, 8A,8B,9,10, 11	1*,2,3,7*, 8A,8B,9, 10,11	1*,2,3,7*, 8A,8B,9,10, 11	1*,2,3,7*, 8A,8B,9, 10,11
7	Group A test requirements	1,2,3,4**,7, 8A,8B,9,10, 11	1,2,3,4**,7, 8A,8B,9,10, 11	1,2,3,4**,7, 8A,8B,9,10, 11	1,2,3,4**,7, 8A,8B,9,10, 11	1,2,3,4**,7, 8A,8B,9,10, 11
8	Group B end-point electrical parameters			1,2,3,7, 8A,8B,9, 10,11 Δ		
9	Group C end-point electrical parameters	2,3,7, 8A,8B	1,2,3,7, 8A,8B Δ		1,2,3,7, 8A,8B Δ	1,2,3,7, 8A,8B,9, 10,11 Δ
10	Group D end-point electrical parameters	2,3, 8A,8B	2,3, 8A,8B	2,3, 8A,8B	2,3, 8A,8B	2,3, 8A,8B
11	Group E end-point electrical parameters	1,7,9	1,7,9	1,7,9	1,7,9	1,7,9

1/ Blank spaces indicate tests are not applicable.

2/ Any or all subgroups may be combined when using high-speed testers.

3/ Subgroups 7 and 8 functional tests shall verify the truth table.

4/ * indicates PDA applies to subgroup 1 and 7.

5/ ** see 4.4.1e.

6/ Δ indicates delta limit (see table IIB) shall be required where specified, and the delta values shall be computed with reference to the previous interim electrical parameters (see line 1).

7/ See 4.4.1d.

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TABLE IIB. Delta limits at +25°C.

Test 1/	Device types
	All
I_{CC2} standby	±10% of specified value in table I
I_{LI}	±10% of specified value in table I
I_{LO}	±10% of specified value in table I

1/ The above parameters shall be recorded before and after the required burn-in and life tests to determine the delta

4.2.1 Additional criteria for device classes M, B, and S - Continued.

- b. For device class M, the test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. For device classes B and S, the test circuit shall be submitted to the qualifying activity. For device classes M, B, and S, the test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1015.

(1) Static burn-in for device classes S (method 1015 of MIL-STD-883, test condition A).

- (a) All inputs shall be connected to GND. Outputs may be open or connected to 4.5 V minimum. Resistors R1 are optional on both inputs and outputs, and required on outputs connected to $V_{CC} \pm 0.5$ V. R1 = 220Ω to 47 kΩ. For static II burn-in, reverse all input connections (i.e., V_{SS} to V_{CC}).
- (b) V_{CC} = 4.5 V minimum.
- (c) Ambient temperature (T_A) shall be +125°C minimum.
- (d) Test duration for the static test shall be 48 hours minimum. The 48 hour burn-in shall be broken into two sequences of 24 hours each (static I and static II) followed by interim electrical measurements.

(2) Dynamic burn-in for device classes M, B, and S (method 1015 of MIL-STD-883, test condition D or F) using the circuit reference in 4.2.1b herein.

c. Interim and final electrical parameters shall be as specified in table IIA herein.

d. For classes S and B devices, post dynamic burn-in electrical parameter measurements may, at the manufacturer's option, be performed separately or included in the final electrical parameter requirements.

4.2.2 Additional criteria for device classes Q and V.

- a. The burn-in test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-I-38535. The burn-in test circuit shall be maintained under document revision level control of the device manufacturer's Technology Review Board (TRB) in accordance with MIL-I-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1015.

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4.2.2 Additional criteria for device classes Q and V - continued.

- b. Interim and final electrical test parameters shall be as specified in table IIA herein.
- c. Additional screening for device class V beyond the requirements of device class Q shall be as specified in appendix B of MIL-I-38535.

4.2.3 Percent defective allowable (PDA).

- a. The PDA for class S devices shall be 5 percent for static burn-in and 5 percent for dynamic burn-in, based on the exact number of devices submitted to each separate burn-in.
- b. The PDA for class B devices shall be in accordance with MIL-M-38510 for dynamic burn-in.
- c. Static burn-in I and II failures shall be cumulative for determining PDA.
- d. Those devices whose measured characteristics, after burn-in, exceed the specified delta limits or electrical parameter limits specified in table I, subgroup 1, are defective and shall be removed from the lot. The verified failures divided by the total number of devices in the lot initially submitted to burn-in shall be used to determine the percent defective for the lot and the lot shall be accepted or rejected based on the specified PDA.
- e. The PDA for device classes Q and V shall be in accordance with MIL-I-38535 for dynamic burn-in.

4.3 Qualification inspection.

4.3.1 Qualification inspection for device classes B and S. Qualification inspection for device classes B and S shall be in accordance with MIL-M-38510. Inspections to be performed shall be those specified in method 5005 of MIL-STD-883 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.5). Qualification data for subgroups 7, 8A, and 8B shall be attributes only.

4.3.1.1 Qualification extension for device class B or S. When authorized by the qualifying activity, if a manufacturer qualifies one device type which is identical (i.e., same die), to other device types on this specification, the slower device types may be part I qualified, upon the request of the manufacturer, without any further testing. The faster device types may be part I qualified by performing only group A qualification testing.

4.3.2 Qualification inspection for device classes Q and V. Qualification inspection for device classes Q and V shall be in accordance with MIL-I-38535. Inspections to be performed shall be those specified in MIL-I-38535 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.5).

4.4 Conformance inspection. Quality conformance inspection for device class M shall be in accordance with MIL-STD-883 (see 3.1 herein) and as specified herein. Quality conformance inspection for device classes B and S shall be in accordance with MIL-M-38510 and as specified herein. Inspections to be performed for device classes M, B, and S shall be those specified in method 5005 of MIL-STD-883 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.5). Technology conformance inspection for classes Q and V shall be in accordance with MIL-I-38535 including groups A, B, C, D, and E inspections and as specified herein except where option 2 of MIL-I-38535 permits alternate in-line control testing.

4.4.1 Group A inspection.

- a. Tests shall be as specified in table IIA herein.
- b. Subgroups 5 and 6 of table I of method 5005 of MIL-STD-883 shall be omitted.
- c. For device class M subgroups 7 and 8 tests shall be sufficient to verify the truth table. For device classes B and S subgroups 7 and 8 tests shall be sufficient to verify the truth table as approved by the qualifying activity. For device classes Q and V subgroups 7 and 8 shall include verifying the functionality of the device, these tests shall have been fault graded in accordance with MIL-STD-883, test method 5012 (see 1.5 herein).

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4.4.1 Group A inspection - Continued.

- d. O/V (latch-up) tests shall be measured only for initial qualification and after any design or process changes which may affect the performance of the device. For device class M procedures and circuits shall be maintained under document revision level control by the manufacturer and shall be made available to the preparing activity or acquiring activity upon request. For device classes B and S, the procedures and circuits shall be maintained under document revision control by the manufacturer and shall be made available to the qualifying activity upon request. For device classes Q and V, the procedures and circuits shall be maintained under the control of the device manufacturer's (TRB) in accordance with MIL-I-38535 and shall be made available to the preparing activity or acquiring activity upon request. Testing shall be on all pins, on 5 devices with zero failures. Latch-up test shall be considered destructive. Information contained in JEDEC standard number 17 may be used for reference.
- e. Subgroup 4 (C_{IN} and C_{OUT} measurements) shall be measured only for initial qualification and after any process or design changes which may affect input or output capacitance. Capacitance shall be measured between the designated terminal and GND at a frequency of 1 MHz. Sample size is fifteen devices with no failures, and all input and output terminals tested.

4.4.2 Group B inspection. The group B inspection end-point electrical parameters shall be as specified in table IIA herein.

- a. For device class S only steady-state life test circuits shall be conducted using test condition D and the circuit described in 4.2.1b herein, or equivalent as approved by the qualifying activity.
- b. For device class S only, end-point electrical parameters shall be as specified in table IIA herein. Delta limits shall apply only to subgroup 5 of group B inspections and shall consist of tests specified in table IIB herein.

4.4.3 Group C inspection. The group C inspection end-point electrical parameters shall be as specified in table IIA herein. Delta limits shall apply only to subgroup 1 of group C inspection and shall consist of tests specified in table IIB herein.

4.4.3.1 Additional criteria for device classes M, B, and S. Steady-state life test conditions, method 1005 of MIL-STD-883:

- a. Test condition D. For device class M, the test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. For device class B, the test circuit shall be submitted to the qualifying activity. For device classes M and B, the test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1005.
- b. $T_A = +125^{\circ}\text{C}$, minimum.
- c. Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

4.4.3.2 Additional criteria for device classes Q and V. The steady-state life test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-I-38535. The test circuit shall be maintained under document revision level control by the device manufacturer's TRB in accordance with MIL-I-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1005.

4.4.4 Group D inspection. For group D inspection end-point electrical parameters shall be as specified in table IIA herein.

4.4.5 Group E inspection. Group E inspection is required only for parts intended to be marked as radiation hardness assured (see 3.5 herein). RHA levels for device classes B, S, Q, and V shall be M, D, R, and H and for device class M shall be M and D.

- a. End-point electrical parameters shall be as specified in table IIA herein.

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4.4.5 Group E inspection - Continued.

- b. For device classes M, B, and S, the devices shall be subjected to radiation hardness assured tests as specified in MIL-M-38510 for the RHA level being tested. For device classes Q and V, the devices or test vehicle shall be subjected to radiation hardness assured tests as specified in MIL-I-38535 for the RHA level being tested. All device classes must meet the postirradiation end-point electrical parameter limits as defined in table I at $T_A = +25^\circ\text{C} \pm 5^\circ\text{C}$, after exposure, to the subgroups specified in table IIA herein.

- c. When specified in the purchase order or contract, a copy of the RHA delta limits shall be supplied.

4.5 Delta measurements for device classes B, S, Q, and V. Delta measurements, as specified in table IIA, shall be made and recorded before and after the required burn-in screens and steady-state life tests to determine delta compliance. The electrical parameters to be measured, with associated delta limits, are listed in table IIB. The manufacturer may, at his option, either perform delta measurements or within 24 hours after life test, perform final electrical parameter tests, subgroups 1, 7, and 9.

5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-M-38510 for device classes M, B, and S and MIL-I-38535 for device classes Q and V.

6. NOTES

6.1 Intended use. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.

6.1.1 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.

6.1.2 Substitutability. Device classes B and Q devices will replace device class M devices.

6.2 Configuration control of SMD's. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished in accordance with MIL-STD-481 using DD Form 1693, Engineering Change Proposal (Short Form).

6.3 Record of users. Military and industrial users shall inform Defense Electronics Supply Center when a system application requires configuration control and which SMD's are applicable to that system. DESC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronic devices (FSC 5962) should contact DESC-EC, telephone (513) 296-6047.

6.4 Comments. Comments on this drawing should be directed to DESC-EC, Dayton, Ohio 45444, or telephone (513) 296-6047.

6.5 Abbreviations, symbols, and definitions. The abbreviations, symbols, and definitions used herein are defined in MIL-M-38510, MIL-STD-1331, and as follows:

C_{IN}	C_{OUT}	Input and bidirectional output, terminal-to-GND capacitance
GND		Ground zero voltage potential
I_{CC}		Supply current
I_{LI}		Input leakage current
I_{LO}		Output leakage current
T_C		Case temperature
T_A		Ambient temperature
V_{CC}		Positive supply voltage
V_{IH}		Input high voltage
V_{IL}		Input low voltage
V_{OH}		Output high voltage
V_{OL}		Output low voltage
V_{SS}		Ground supply voltage
O/V		Latch-up over-voltage

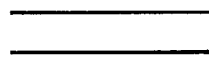
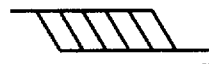
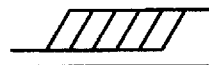
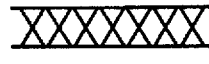
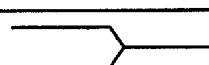
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6.5.1 Timing Limits. The table of timing values shows either a minimum or a maximum limit for each parameter. Input requirements are specified from the external system point of view. Thus, address setup time is shown as a minimum since the system must supply at least that much time (even though most devices do not require it). On the other hand, responses from the memory are specified from the device point of view. Thus, the access time is shown as a maximum since the device never provides data later than that time.

6.5.2 Waveforms.

Waveform symbol	Input	Output
	MUST BE VALID	WILL BE VALID
	CHANGE FROM H TO L	WILL CHANGE FROM H TO L
	CHANGE FROM L TO H	WILL CHANGE FROM L TO H
	DON'T CARE ANY CHANGE PERMITTED	CHANGING STATE UNKNOWN
		HIGH IMPEDANCE

6.6 One part - one part number system. The one part - one part number system described below has been developed to allow for transitions between identical generic devices covered by the four major microcircuit requirements documents (MIL-M-38510, MIL-H-38534, MIL-I-38535, and 1.2.1 of MIL-STD-883) without the necessity for the generation of unique PIN's. The four military requirements documents represent different class levels, and previously when a device manufacturer upgraded military product from one class level to another, the benefits of the upgraded product were unavailable to the Original Equipment Manufacturer (OEM), that was contractually locked into the original unique PIN. By establishing a one part number system covering all four documents, the OEM can acquire to the highest class level available for a given generic device to meet system needs without modifying the original contract parts selection criteria.

<u>Military documentation format</u>	<u>Example PIN under new system</u>	<u>Manufacturing source listing</u>	<u>Document Listing</u>
New MIL-M-38510 Military Detail Specifications (in the SMD format)	5962-XXXXXZZ(B or S)YY	QPL-38510 (Part 1 or 2)	MIL-BUL-103
New MIL-H-38534 Standardized Military Drawings	5962-XXXXXZZ(H or K)YY	QML-38534	MIL-BUL-103
New MIL-I-38535 Standardized Military Drawings	5962-XXXXXZZ(Q or V)YY	QML-38535	MIL-BUL-103
New 1.2.1 of MIL-STD-883 Standardized Military Drawings	5962-XXXXXZZ(M)YY	MIL-BUL-103	MIL-BUL-103

6.7 Sources of supply.

6.7.1 Sources of supply for device classes B and S. Sources of supply for device classes B and S are listed in QPL-38510.

6.7.2 Sources of supply for device classes Q and V. Sources of supply for device classes Q and V are listed in QML-38535. The vendors listed in QML-38535 have submitted a certificate of compliance (see 3.6 herein) to DESC-EC and have agreed to this drawing.

6.7.3 Approved sources of supply for device class M. Approved sources of supply for class M are listed in MIL-BUL-103. The vendors listed in MIL-BUL-103 have agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DESC-EC.

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